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v06.0611



GaAs InGaP HBT MMIC POWER AMPLIFIER, 5 - 6 GHz

Typical Applications

The HMC406MS8G(E) is ideal for:

- WiMAX & WiLAN
- DSRC
- Military & Maritime
- Private Mobile Radio
- UNII & ISM

Features

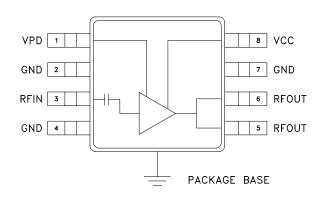
Gain: 17 dB

Saturated Power: +29 dBm

38% PAE

Supply Voltage: +5V
Power Down Capability
Low External Part Count

Functional Diagram



General Description

The HMC406MS8G(E) is a high efficiency GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC Power amplifier which operates between 5 and 6 GHz. The amplifier is packaged in a low cost, surface mount 8 leaded package with an exposed base for improved RF and thermal performance. With a minimum of external components, the amplifier provides 17 dB of gain and +29 dBm of saturated power at 38% PAE from a +5V supply voltage. Vpd can be used for full power down or RF output power/current control.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vs = 5V, Vpd = 5V

Parameter		Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range			5 - 6	5 - 6 5.7 - 5.9		GHz		
Gain		13	16	21	14	17	21	dB
Gain Variation Over Temperature			0.03	0.04		0.03	0.04	dB/ °C
Input Return Loss			10			11		dB
Output Return Loss			8			9		dB
Output Power for 1 dB Compression (P1dB)		21	24		24	27		dBm
Saturated Output Power (Psat)			27			29		dBm
Output Third Order Intercept (IP3)		34	38		34	38		dBm
Noise Figure			6.0			6.0		dB
Supply Current (Icq)	/pd = 0V/5V		0.002 / 300			0.002 / 300		mA
Control Current (Ipd)	Vpd = 5V		7			7		mA
Switching Speed	tON, tOFF		35			35		ns

HMC406* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS 🖳

View a parametric search of comparable parts.

EVALUATION KITS

· HMC406MS8G Evaluation Board

DOCUMENTATION

Application Notes

 AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers

Data Sheet

· HMC406 Data Sheet

TOOLS AND SIMULATIONS 🖵

· HMC406 S-Parameter

REFERENCE MATERIALS 🖳

Quality Documentation

- HMC Legacy PCN: MS##, MS##E and MS##G,MS##GE packages - Relocation of pre-existing production equipment to new building
- Package/Assembly Qualification Test Report: MS8G (QTR: 2014-00393)
- PCN: MS, QS, SOT, SOIC packages Sn/Pb plating vendor change
- Semiconductor Qualification Test Report: GaAs HBT-B (QTR: 2013-00229)

DESIGN RESOURCES

- HMC406 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

DISCUSSIONS 🖳

View all HMC406 EngineerZone Discussions.

SAMPLE AND BUY 🖳

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK 🖳

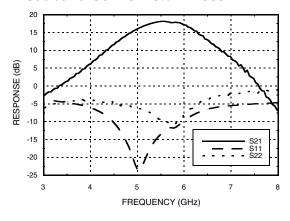
Submit feedback for this data sheet.



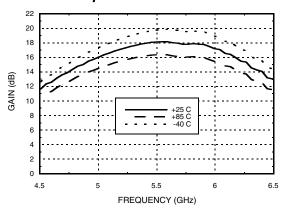


GaAs InGaP HBT MMIC POWER AMPLIFIER, 5 - 6 GHz

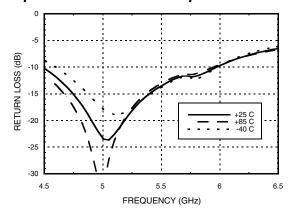
Broadband Gain & Return Loss



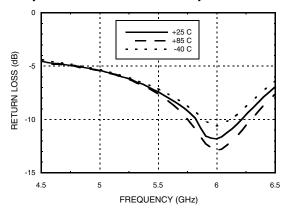
Gain vs. Temperature



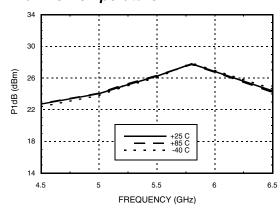
Input Return Loss vs. Temperature



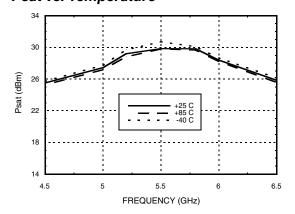
Output Return Loss vs. Temperature



P1dB vs. Temperature



Psat vs. Temperature

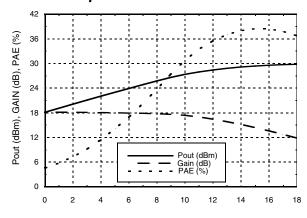




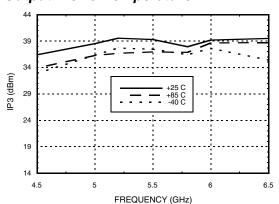


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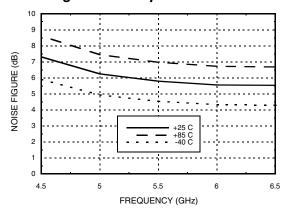
Power Compression @ 5.8 GHz



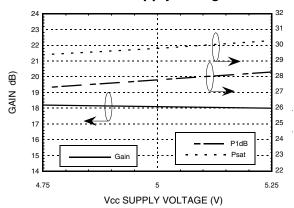
Output IP3 vs. Temperature



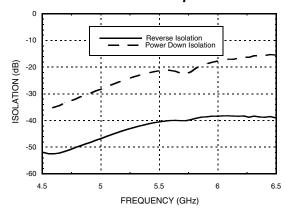
Noise Figure vs. Temperature



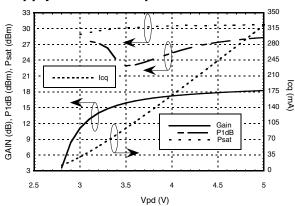
Gain & Power vs. Supply Voltage



Reverse Isolation vs. Temperature



Gain, Power & Quiescent Supply Current vs. Vpd @ 5.8 GHz







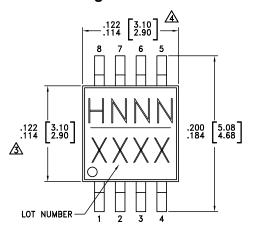
GaAs InGaP HBT MMIC POWER AMPLIFIER, 5 - 6 GHz

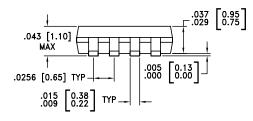
Absolute Maximum Ratings

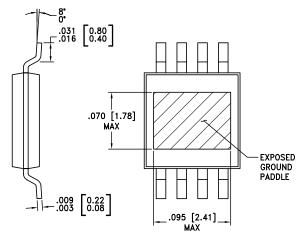
Collector Bias Voltage (Vcc)	+5.5V	
Control Voltage (Vpd)	+5.5V	
RF Input Power (RFIN)(Vs = Vpd = +5V)	+20 dBm	
Junction Temperature	150 °C	
Continuous Pdiss (T = 85 °C) (derate 32 mW/°C above 85 °C)	2.1 W	
Thermal Resistance (junction to ground paddle)	31 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85° C	



Outline Drawing







NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- ⚠ DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 5. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]	
HMC406MS8G	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H406 XXXX	
HMC406MS8GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	<u>H406</u> XXXX	

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX



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Pin Descriptions

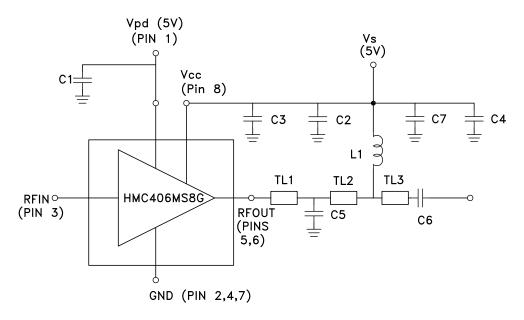
Pin Number	Function	Description	Interface Schematic
1	Vpd	Power Control Pin. For maximum power, this pin should be connected to 5V. A higher voltage is not recommended. For lower idle current, this voltage can be reduced.	OVPD
2, 4, 7	GND	Ground: Backside of package has exposed metal ground slug that must be connected to ground thru a short path. Vias under the device are required.	GND =
3	RFIN	This pin is AC coupled and matched to 50 Ohms.	RFIN ○──
5, 6	RFOUT	RF output and bias for the output stage. The power supply for the output device needs to be supplied to these pins.	ORFOUT ORFOUT
8	Vcc	Power supply voltage for the first amplifier stage. An external bypass capacitor of 330 pF is required. This capacitor should be placed as close to the devices as possible.	ovcc





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Application Circuit



Note 1: C3 should be located < 0.020" from Pin 8 (Vcc)

Note 2: C2 should be located < 0.020" from L1.

	TL1	TL2	TL3
Impedance	50 ohm	50 ohm	50 ohm
Physical Length	0.0443"	0.2556"	0.1000"
Electrical Length @ 5.5 GHz	11.3°	65.2°	25.5°
Measurement	Edge of package pin to center of capacitor C5.	Center of capacitor C5 to center of bias line.	Center of bias line to edge of capacitor C6.

PCB Material: 10 mil Rogers 4350 or Arlon 25FR

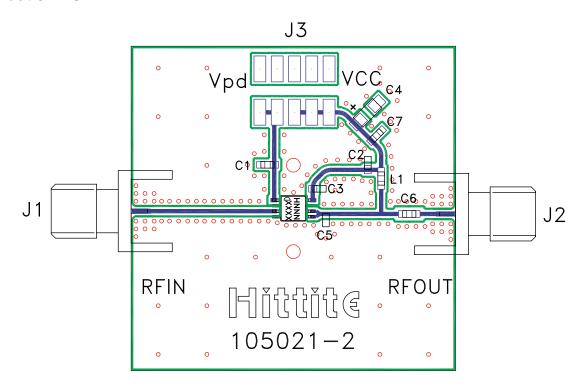


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Evaluation PCB



List of Materials for Evaluation PCB 104989 [1]

Item	Description	
J1 - J2	PCB Mount SMA RF Connector	
J3	2mm DC Header	
C1 - C3	330 pF Capacitor, 0603 Pkg.	
C4	2.2 µF Capacitor, Tantalum	
C5	0.6 pF Capacitor, 0603 Pkg.	
C6	1.6 pF Capacitor, 0603 Pkg.	
C7	100 pF Capacitor, 0603 Pkg.	
L1	3.9 nH Inductor, 0603 Pkg.	
U1	HMC406MS8G(E) Amplifier	
PCB [2]	105021 Eval Board	

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Roger 4350 or Arlon 25FR



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Notes: